

Vishay Semiconductors

Small Signal Fast Switching Diodes



FEATURES

- Silicon epitaxial planar diode
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS

HALOGEN

FREE

APPLICATIONS

• Extreme fast switches

ADDITIONAL RESOURCES



MECHANICAL DATA

Case: DO-35 (DO-204AH)
Weight: approx. 125 mg
Cathode band color: black
Packaging codes / options:

TR/10K per 13" reel (52 mm tape), 50K/box TAP/10K per ammopack (52 mm tape), 50K/box

PARTS TABLE					
PART	ORDERING CODE	TYPE MARKING	CIRCUIT CONFIGURATION	REMARKS	
1N4151	1N4151TR or 1N4151TAP	1N4151	Single	Tape and reel / ammopack	

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Repetitive peak reverse voltage		V_{RRM}	75	V	
Reverse voltage		V _R	50	V	
Peak forward surge current	t _p = 1 μs	I _{FSM}	2	Α	
Repetitive peak forward current		I _{FRM}	500	mA	
Forward continuous current		I _F	300	mA	
Average forward current	V _R = 0	I _{F(AV)}	150	mA	
Dever dissination	I = 4 mm, T _L = 45 °C	P _{tot}	440	mW	
Power dissipation	I = 4 mm, T _L ≤ 25 °C	P _{tot}	500	mW	

THERMAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)					
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT	
Thermal resistance junction to ambient air	I = 4 mm, T _L = constant	R _{thJA}	350	K/W	
Junction temperature		Tj	175	°C	
Storage temperature range		T _{stg}	-65 to +175	°C	



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ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	I _F = 50 mA	V _F		0.880	1	V
Reverse current	V _R = 50 V	I _R		14	50	nA
Reverse current	V _R = 50 V, T _j = 150 °C	I _R			50	μΑ
Breakdown voltage	$I_R = 5 \mu A$	V _(BR)	75			V
Diode capacitance	$V_R = 0 \text{ V, f} = 1 \text{ MHz,} $ $V_{HF} = 50 \text{ mV}$	C _D			2	pF
Davaraa raaayan tima	$I_F = I_R = 10 \text{ mA},$ $I_R = 1 \text{ mA}$	t _{rr}			4	ns
Reverse recovery time	$I_F = 10 \text{ mA}, V_R = 6 \text{ V},$ $i_R = 0.1 \text{ x } I_R, R_L = 100 \Omega$	t _{rr}			2	ns

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

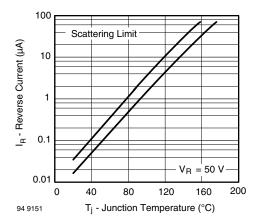


Fig. 1 - Reverse Current vs. Junction Temperature

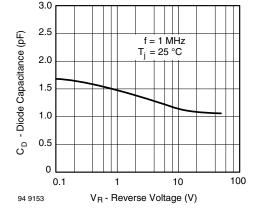


Fig. 3 - Diode Capacitance vs. Reverse Voltage

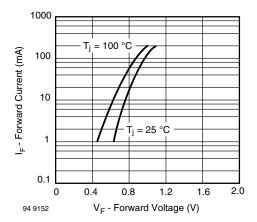
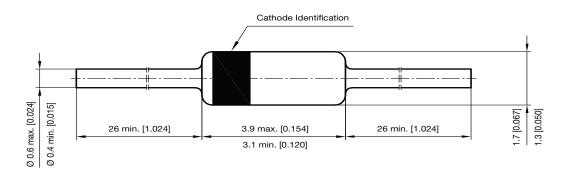


Fig. 2 - Forward Current vs. Forward Voltage



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PACKAGE DIMENSIONS in millimeters (inches): DO-35 (DO-204AH)



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RFUH20TB3S BAS 28 E6327 BAV199-TP BAW56DWQ-7-F BAW75-TAP MM230L-CAA IDW40E65D1 JAN1N3600 LL4151-GS18

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